

**AMENDMENTS TO THE SPECIFICATION**

Please replace the cover page with the following rewritten cover page:

**METHOD FOR PREPARATION OF SEMICONDUCTIVE FILMS**

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Please replace the paragraph on page 4 with the following rewritten paragraph:

The process of the present invention uses a soluble polymer to assist in the deposition of an initial intermediate metal oxide. Thus, the process can be referred to as a polymer assisted solution deposition process. Inclusion of a soluble polymer with a soluble metal complex or complexes promotes better distribution of the materials during the deposition. Where the polymer and metal complex or complexes are water-soluble, the process can provide an organic-solvent free process. Subsequently, the polymer can be removed by heating at sufficiently high temperatures to leave the intermediate metal oxide film. By using a soluble polymer in conjunction with one or more soluble metal complexes, single or mixed metal oxide films can be prepared. The overall process is an aqueous process that can be organic solvent free. Where the

present invention involves an aqueous process, such a process can be conducted at pH conditions of from about 4 to about 7, more preferably from about 5 to about 7. Such pH ranges can avoid any drawbacks associated with highly acidic processes.